Recognizes, on an annual basis, the most significant contribution in a paper published in the IEEE Transactions on Terahertz Science and Technology.

Is Awarded to Yasushi Koyama, Yuki Kitazawa, Koji Yukimasa, Tatsuro Uchida, Takeshi Yoshioka, Kokichi Fujimoto, Takahiro Sato, Jun Iba, Katsuhito Sakurai, Takeshi Ichikawa for their paper entitled "A High-Power Terahertz Source Over 10 mW at 0.45 THz Using an Active Antenna Array With Integrated Patch Antennas and Resonant-Tunneling Diodes", IEEE Transactions on Terahertz Science and Technology, vol.12, no. 5, Sep. 2022.



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